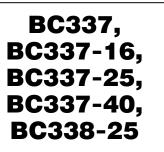
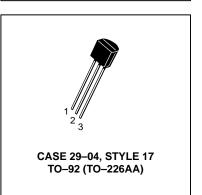
Amplifier Transistors NPN Silicon

MAXIMUM RATINGS

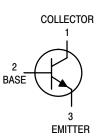
| Rating | Symbol | BC337 | BC338 | Unit |
|---|-----------------------------------|-------------|-------|---------------|
| Collector–Emitter Voltage | VCEO | 45 | 25 | Vdc |
| Collector-Base Voltage | VCBO | 50 | 30 | Vdc |
| Emitter-Base Voltage | VEBO | 5.0 | | Vdc |
| Collector Current – Continuous | IC | 800 | | mAdc |
| Total Device Dissipation @ T _A = 25°C Derate above 25°C | PD | 625 5.0 | | mW mW/°C |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | PD | 1.5 12 | | Watt mW/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | –55 to +150 | | °C |





THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|------|------|
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 200 | °C/W |
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 83.3 | °C/W |



ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

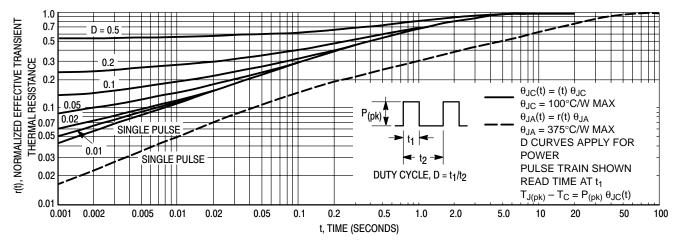
| Characteristic | | Symbol | Min | Тур | Max | Unit |
|--|----------------|----------------------|----------|-----|------------|------|
| OFF CHARACTERISTICS | | · · · · · | | | - | |
| Collector–Emitter Breakdown Voltage ($I_C = 10 \text{ mA}, I_B = 0$) | BC337 BC338 | V(BR)CEO | 45 25 | | | Vdc |
| Collector–Emitter Breakdown Voltage $(I_C = 100 \ \mu A, I_E = 0)$ | BC337 BC338 | V(BR)CES | 50 30 | | | Vdc |
| Emitter–Base Breakdown Voltage ($I_E = 10 \ \mu A, I_C = 0$) | | V _{(BR)EBO} | 5.0 | - | - | Vdc |
| Collector Cutoff Current ($V_{CB} = 30 \text{ V}, I_E = 0$) ($V_{CB} = 20 \text{ V}, I_E = 0$) | BC337 BC338 | ICBO | - | | 100 100 | nAdc |
| Collector Cutoff Current ($V_{CE} = 45 V, V_{BE} = 0$) ($V_{CE} = 25 V, V_{BE} = 0$) | BC337 BC338 | ICES | - | | 100 100 | nAdc |
| Emitter Cutoff Current ($V_{EB} = 4.0 \text{ V}, I_C = 0$) | | IEBO | - | - | 100 | nAdc |

© Semiconductor Components Industries, LLC, 2001 October, 2001 – Rev. 2 1

BC337, BC337-16, BC337-25, BC337-40, BC338-25

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

| Characteristic | | Symbol | Min | Тур | Max | Unit |
|---|--|---------------------|--------------------------------|------------------|--------------------------|------|
| ON CHARACTERISTICS | | | | | | |
| DC Current Gain (I _C = 100 mA, V _{CE} = 1.0 V) (I _C = 300 mA, V _{CE} = 1.0 V) | BC337 BC337–16 BC337–25/BC338–25 BC337–40 | hFE | 100 100 160 250 60 | - - - - | 630 250 400 630 | _ |
| Base-Emitter On Voltage ($I_C = 300 \text{ mA}, V_{CE} = 1.0 \text{ V}$) | | V _{BE(on)} | - | - | 1.2 | Vdc |
| Collector–Emitter Saturation Voltage $(I_C = 500 \text{ mA}, I_B = 50 \text{ mA})$ | | VCE(sat) | - | _ | 0.7 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | | | | | | |
| Output Capacitance (V _{CB} = 10 V, I _E = 0, f = 1.0 MHz) | | C _{ob} | - | 15 | - | pF |
| Current–Gain – Bandwidth Product (I _C = 10 mA, V _{CE} = 5.0 V, f = 100 MHz) | | fT | - | 210 | - | MHz |





BC337, BC337-16, BC337-25, BC337-40, BC338-25

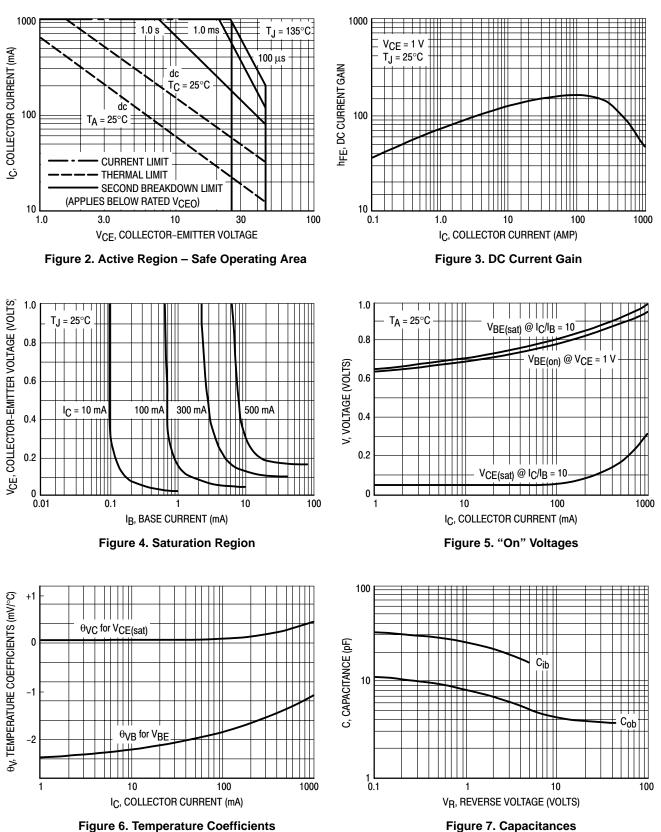
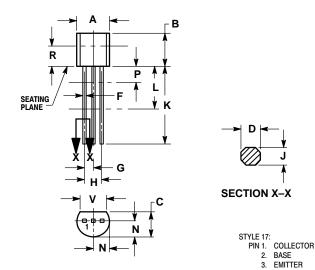


Figure 7. Capacitances

PACKAGE DIMENSIONS

CASE 029-04 (TO-226AA) ISSUE AD



NOTES: NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R

IS UNCONTROLLED. DIMENSION F APPLIES BETWEEN P AND L.

DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM

| | INCHES | | MILLIMETERS | | |
|-----|--------|-------|-------------|------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.175 | 0.205 | 4.45 | 5.20 | |
| В | 0.170 | 0.210 | 4.32 | 5.33 | |
| С | 0.125 | 0.165 | 3.18 | 4.19 | |
| D | 0.016 | 0.022 | 0.41 | 0.55 | |
| F | 0.016 | 0.019 | 0.41 | 0.48 | |
| G | 0.045 | 0.055 | 1.15 | 1.39 | |
| Н | 0.095 | 0.105 | 2.42 | 2.66 | |
| J | 0.015 | 0.020 | 0.39 | 0.50 | |
| K | 0.500 | | 12.70 | | |
| L | 0.250 | | 6.35 | | |
| N | 0.080 | 0.105 | 2.04 | 2.66 | |
| Ρ | | 0.100 | | 2.54 | |
| R | 0.115 | | 2.93 | | |
| ۷ | 0.135 | | 3.43 | | |

ON Semiconductor and 🖤 are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

Literature Fulfillment:

Literature Distribution Center for ON Semiconductor

P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: ONlit@hibbertco.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

JAPAN: ON Semiconductor, Japan Customer Focus Center 4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan 141-0031 Phone: 81-3-5740-2700 Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local Sales Representative.